

## **IXFJ26N50P3 Datasheet**



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DiGi Electronics Part Number IXFJ26N50P3-DG

Manufacturer IXYS

Manufacturer Product Number IXFJ26N50P3

Description MOSFET N-CH 500V 14A TO247

Detailed Description N-Channel 500 V 14A (Tc) 180W (Tc) Through Hole

TO-247 (IXTH)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFJ26N50P3	IXYS
Series:	Product Status:
HiPerFET™, Polar3™	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
500 V	14A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	265mOhm @ 13A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 4mA	42 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	2220 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	180W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247 (IXTH)	TO-247-3
Base Product Number:	
IXFJ26	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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